# **ASM3P2872A**





# **Peak EMI Reducing Solution**

#### **Features**

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3V / 2.5V supply.
- Operating current less than 6mA.
- CMOS design.
- Input frequency range: 13MHz to 30MHz for 2.5V
  13MHz to 30MHz for 3.3V
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: -1.25% @ 22MHz.
- Available in 6L-TSOP (6L-TSOT-23) packages.

#### **Product Description**

The ASM3P2872A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2872A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2872A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2872A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

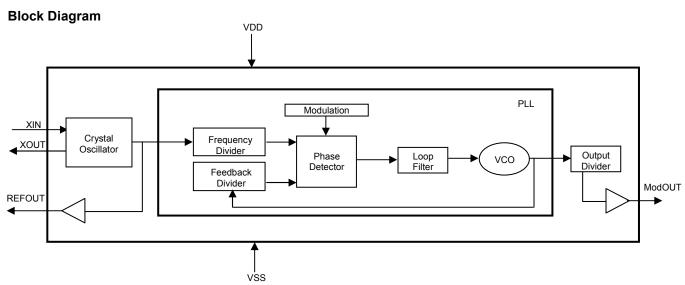
The ASM3P2872A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

### **Applications**

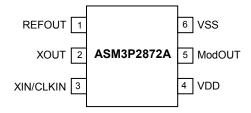
The ASM3P2872A is targeted towards all portable devices like MP3 players, Notebooks and digital still cameras.

#### **Key Specifications**

Description	Specification
Supply voltages	VDD = 3.3V /2.5V
Cycle-to-Cycle Jitter	±200pS (Typ)
Output Duty Cycle	45/55% (worst case)
Modulation Rate Equation	F <sub>IN</sub> /640
Frequency Deviation	-1.25% @ 22MHz



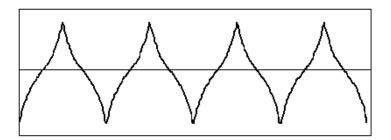
# Pin Configuration (6L-TSOP Package)



**Pin Description** 

Pin#	Pin Name	Туре	Description			
1	REFOUT	0	Buffered output of the input frequency.			
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.			
3	XIN / CLKIN	KIN Crystal connection or external reference frequency input. This pin has dual function can be connected either to an external crystal or an external reference clock.				
4	VDD	Р	Power supply for the entire chip.			
5	ModOUT	0	Spread spectrum clock output.			
6	VSS	Р	Ground connection.			

## **Modulation Profile**



**Specifications** 

	Description	Specification
Frequency Range	For 2.5V Supply	13MHz < CLKIN < 30MHz
	For 3.3V Supply	13MHz < CLKIN < 30MHz
Modulation Equation		F <sub>IN</sub> /640
Frequency Deviation		-1.25% @ 22MHz

**Absolute Maximum Ratings** 

Symbol	Parameter	Rating	Unit				
VDD, V <sub>IN</sub>	Voltage on any pin with respect to Ground	-0.5 to +4.6	V				
T <sub>STG</sub>	Storage temperature	-65 to +125	C				
Ts	Max. Soldering Temperature (10 sec)	260	C				
TJ	Junction Temperature	150	C				
T <sub>DV</sub> Static Discharge Voltage (As per JEDEC STD22- A114-B) 2 KV							
	Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.						

**Operating Conditions** 

Parameter	Description	Min	Max	Unit
VDD	Supply Voltage	2.375	3.6	V
$T_A$	Operating Temperature (Ambient Temperature)	0	70	$_{\mathcal{C}}$
$C_L$	Load Capacitance		15	pF
C <sub>IN</sub>	Input Capacitance		7	pF

**DC Electrical Characteristics for 2.5V Supply** 

Symbol	Parameter	Min	Тур	Max	Unit
V <sub>IL</sub>	Input low voltage	VSS-0.3		0.8	V
V <sub>IH</sub>	Input high voltage	2.0		VDD+0.3	V
I <sub>IL</sub>	Input low current			-35	μA
I <sub>IH</sub>	Input high current			35	μA
I <sub>XOL</sub>	XOUT output low current (@ 0.5V, VDD = 2.5V)		3		mA
I <sub>XOH</sub>	XOUT output high current (@ 1.8V, VDD = 2.5V)		3		mA
V <sub>OL</sub>	Output low voltage (VDD = 2.5 V, I <sub>OL</sub> = 8mA)			0.6	V
V <sub>OH</sub>	Output high voltage (VDD = 2.5 V, I <sub>OH</sub> = 8mA)	1.8			V
I <sub>DD</sub>	Static supply current <sup>1</sup>		1.1		mA
Icc	Dynamic supply current (2.5V, 30MHz and with no load)		4.0		mA
VDD	Operating voltage	2.375	2.5	2.625	V
t <sub>ON</sub>	Power-up time (first locked cycle after power-up)			5	mS
Z <sub>OUT</sub>	Output impedance		50		Ω
Note: 1. XIN	CLKIN pin is pulled low.		•		

**AC Electrical Characteristics for 2.5V Supply** 

Symbol	Pa	Min	Тур	Max	Unit		
CLKIN	Input frequency		13		30	MHz	
ModOUT	Output frequency		13		30	MHz	
f <sub>d</sub>	Fraguency Deviation	Input Frequency = 13MHz		-1.85		- %	
	Frequency Deviation	Input Frequency = 30MHz		-0.9			
t <sub>LH</sub> <sup>1</sup>	Output rise time (measu	0.7	1.5	1.7	nS		
t <sub>HL</sub> 1	Output fall time (measur	0.5	0.9	1.1	nS		
t <sub>JC</sub>	Jitter (cycle-to-cycle)		±200		pS		
t <sub>D</sub>	Output duty cycle	45	50	55	%		
Note: 1. t <sub>LH</sub> and t <sub>HI</sub>	are measured into a capacitive l	Note: 1. t <sub>LH</sub> and t <sub>HL</sub> are measured into a capacitive load of 15pF.					

**DC Electrical Characteristics for 3.3V Supply** 

Symbol	Parameter	Min	Тур	Max	Unit
V <sub>IL</sub>	Input low voltage	VSS-0.3		0.8	V
$V_{IH}$	Input high voltage	2.0		VDD+0.3	V
I <sub>IL</sub>	Input low current			-35	μA
I <sub>IH</sub>	Input high current			35	μA
I <sub>XOL</sub>	XOUT output low current (@ 0.4V, VDD = 3.3V)		3		mA
I <sub>XOH</sub>	XOUT output high current (@ 2.5V, VDD = 3.3V)		3		mA
V <sub>OL</sub>	Output low voltage (VDD = 3.3 V, I <sub>OL</sub> = 8mA)			0.4	V
V <sub>OH</sub>	Output high voltage (VDD = 3.3 V, I <sub>OH</sub> = 8mA)	2.5			V
I <sub>DD</sub>	Static supply current <sup>1</sup>		1.2		mA
Icc	Dynamic supply current (3.3V, 30MHz and with no load)		5.5		mA
VDD	Operating voltage	2.7	3.3	3.6	V
t <sub>ON</sub>	Power-up time (first locked cycle after power-up)			5	mS
Z <sub>out</sub>	Output impedance		45		Ω
Note: 1. XIN /	CLKIN pin is pulled low.			•	

**AC Electrical Characteristics for 3.3V Supply** 

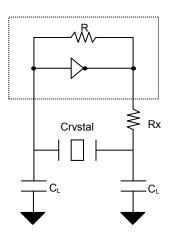
Symbol	Pa	Min	Тур	Max	Unit	
CLKIN	Input frequency		13		30	MHz
ModOUT	Output frequency		13		30	MHz
£	Fraguency Deviation	Input Frequency = 13MHz		-1.85		%
$f_d$	Frequency Deviation Input Frequency = 30MHz		-0.9		70	
t <sub>LH</sub> <sup>1</sup>	Output rise time (measu	Output rise time (measured from 0.8 to 2.0V)			1.7	nS
t <sub>HL</sub> 1	Output fall time (measur	Output fall time (measured at 2.0V to 0.8V)			1.1	nS
t <sub>JC</sub>	Jitter (cycle-to-cycle)		±200		pS	
t <sub>D</sub>	Output duty cycle	45	50	55	%	
Note: 1. t <sub>LH</sub> and t <sub>HL</sub> are	measured into a capacitive load of	<sup>1</sup> 15pF.				

# **Typical Crystal Specifications**

Fundamental AT cut parallel resonant crystal				
Nominal frequency	14.31818MHz			
Frequency tolerance	± 50 ppm or better at 25℃			
Operating temperature range	-25℃ to +85℃			
Storage temperature	-40℃ to +85℃			
Load capacitance(C <sub>P</sub> )	18pF			
Shunt capacitance	7pF maximum			
ESR	25 Ω			

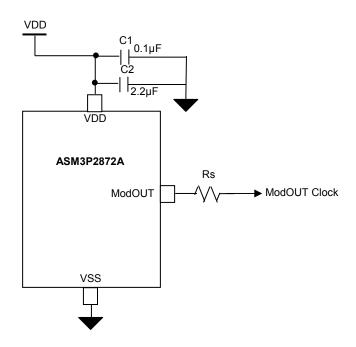
Note: Note: C<sub>L</sub> is Load Capacitance and Rx is used to prevent oscillations at overtone frequency of the Fundamental frequency.

# **Typical Crystal Interface Circuit**



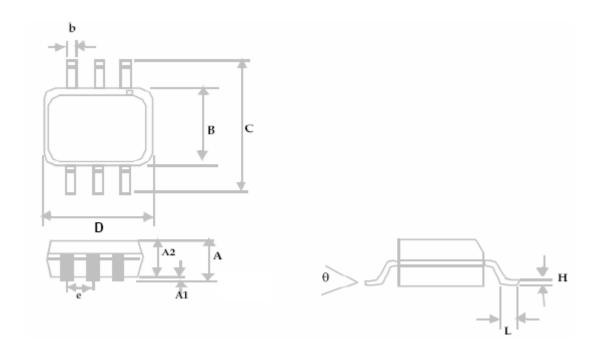
$$\begin{split} C_\text{L} &= 2^*(C_\text{P} - C_\text{S}), \\ \text{Where } C_\text{P} &= \text{Load capacitance of crystal} \\ C_\text{S} &= \text{Stray capacitance due to } C_\text{IN,} \text{ PCB, Trace etc.} \end{split}$$

# **Typical Application Schematic**



# Package Information

# **6L-TSOP Package**



	Dimensions					
Symbol	Inc	hes	Millimeters			
	Min	Max	Min	Max		
Α		0.04		1.00		
A1	0.00	0.004	0.00	0.10		
A2	0.033	0.036	0.84	0.90		
b	0.012	0.02	0.30	0.50		
Н	0.005	BSC	0.127	BSC		
D	0.114	BSC	2.90	BSC		
В	0.06	BSC	1.60	BSC		
е	0.0374	4 BSC	0.950	BSC		
С	0.11	1 BSC 2.80 BSC		0.11 BSC		BSC
L	0.0118	0.02	0.30 0.50			
θ	0°	4°	0°	4°		

ASM3P2872A

#### **Ordering Information**

Part Number	Marking	Package Type	Temperature
ASM3P2872AF-06OR	B4L	6L-TSOP (6L-TSOT-23), TAPE & REEL, Pb Free	0℃ to +70℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

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